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(12) United States Patent Krivokapic

(54) METHOD OF FABRICATING AN ULTRA-THIN FULLY DEPLETED SOI DEVICE WITH T-SHAPED GATE

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- (73) Assignee: Advanced Micro Devices, Inc., Sunnyvale, CA (US)
- (*) Notice: Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 0 days.
- (21) Appl. No.: 10/200,652
- (22) Filed: Jul. 22, 2002

Related U.S. Application Data

- (62) Division of application No. 10/081,104, filed on Feb. 21, 2002, now Pat. No. 6,452,229.
- (51) Int. Cl.⁷ H01L 21/336; H01L 21/00; H01L 21/28
- (52) U.S. Cl. 438/270; 438/297; 438/303; 438/151; 438/572; 438/574; 438/576; 438/580

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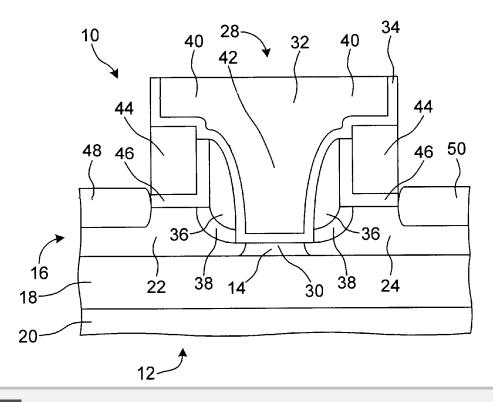
(45) Date of Patent:

Primary Examiner—John F. Niebling Assistant Examiner—Stanetta Isaac (74) Attorney, Agent, or Firm—Renner, Otto, Boisselle & Sklar, LLP

(57) ABSTRACT

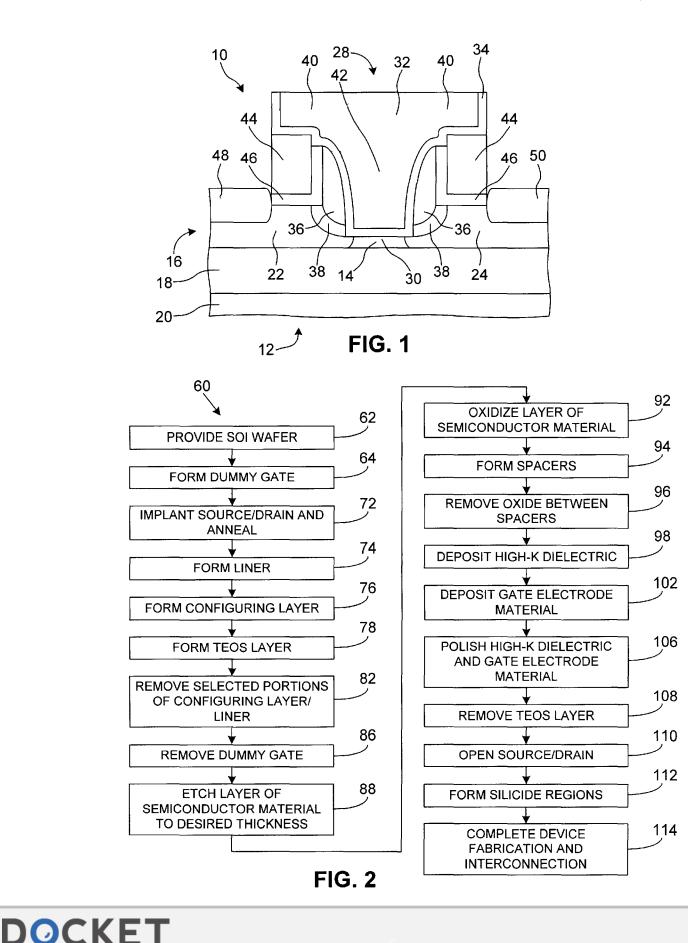
A method of forming a fully depleted semiconductor-oninsulator (SOI) field effect transistor (FET). The method includes forming a T-shaped gate electrode formed at least in part in a recess formed in a layer of semiconductor material and over a body region that is disposed between a source and a drain. The method includes spacing the gate electrode from the body by a gate dielectric made from a high-K material.

15 Claims, 5 Drawing Sheets

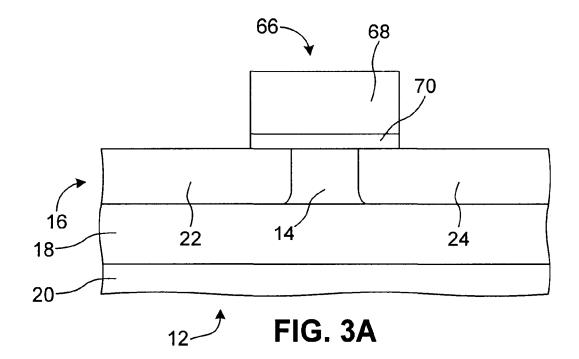


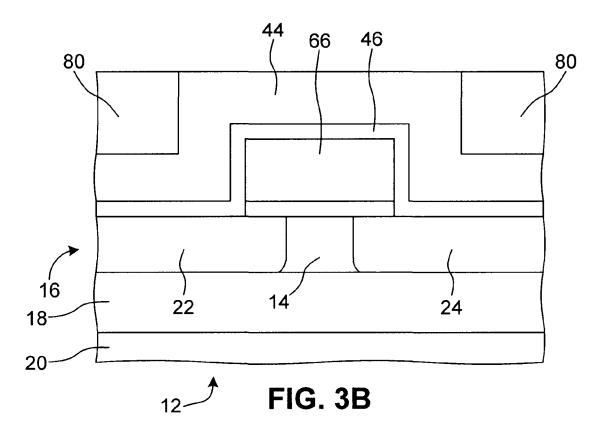
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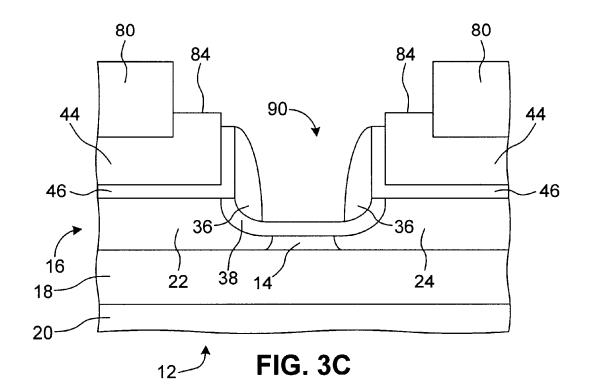
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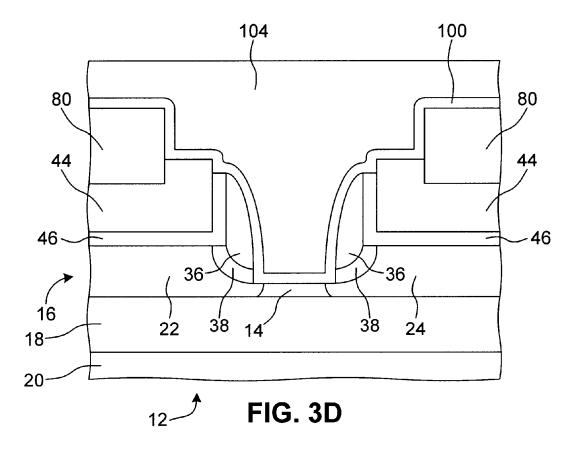


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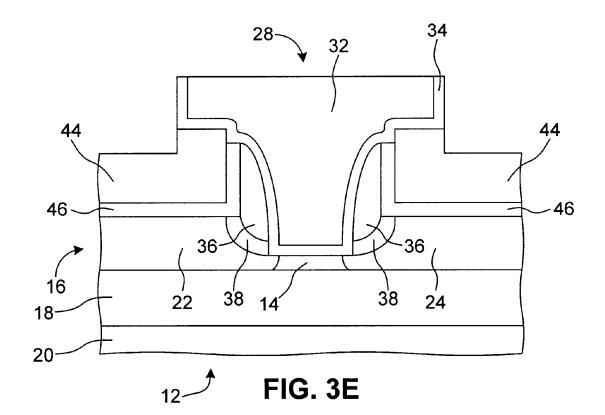


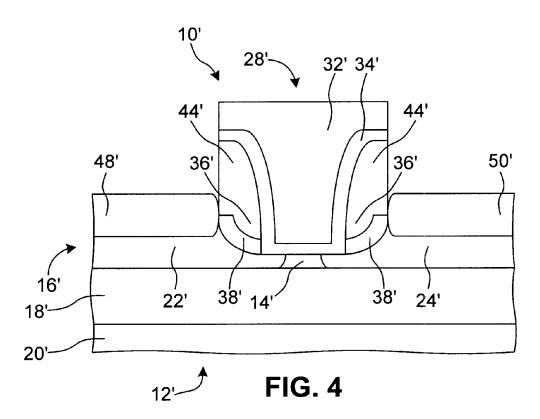






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